

Tribo-Environment Dependent Chemical Modification of Sliding Interfaces in Ultrananocrystalline Diamond Nanowall Film: A Correlation with Friction and Wear

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ABSTRACT: Tribological properties of ultrananocrystalline diamond nanowall (UNCD NW) films were investigated quantitatively in three different and controlled tribo-environmental conditions, proposing the passivation and graphitization mechanisms. However, these mechanisms are rather complicated and possibly can be understood in well-controlled tribological conditions. It was shown that the friction and wear of these films were high in high-

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3 vacuum and room temperature (HV-RT) tribo-condition in which the passivation of carbon
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5 dangling bonds was restricted and frictional shear-induced transformation of sp^3 carbon into
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7 amorphous carbon (a-C) and tetrahedral amorphous carbon (t-aC) was noticed. However, the
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9 friction coefficient was reduced to the ultralow value in ambient atmospheric and room
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11 temperature (AA-RT) tribo-condition. Here, both passivation of dangling bonds through
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13 atmospheric water vapor and graphitization of the contact interfaces were energetically favorable
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15 mechanisms. Furthermore, the conversion of diamond sp^3 into hydrogenated-graphitized phase
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17 was dominating mechanism for observed super-low friction coefficient and ultra-high wear
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19 resistance of films in high-vacuum and high-temperature (HV-HT) tribo-condition. These
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21 mechanisms were comprehensively investigated by micro-Raman and X-ray photoelectron
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23 spectroscopy analyses of the sliding interfaces.
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30 31 **1. INTRODUCTION**

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33 The crystalline diamond films are useful for several applications due to their unique
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35 microstructure and chemical properties. Diamond is a wide band gap material¹ with high thermal
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37 conductivity,² extreme hardness,³ high elastic modulus³ and unique friction and wear
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39 performances.⁴⁻⁶ All these outstanding properties of crystalline diamond are associated to the
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41 sp^3 -hybridized chemical bonding of carbon atoms in cubic tetrahedral unit-cell parameter.^{7,8}
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43 Some of these properties of single crystal and micro/nanocrystalline diamond films were studied
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45 reasonably well. Moreover, recently, field emission^{9,10} and tribological properties^{11,12} of
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47 ultrananocrystalline diamond (UNCD) films were found to be superior as compared to the
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49 micro/nanocrystalline counterpart. Boron enhanced growth of UNCD films showed improvement
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51 in physicochemical and electrochemical properties.^{13,14} This improvement is associated with
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3 unique morphology and microstructure of ultranano diamond grains embedded with wider grain
4 boundaries which occupy short-ranged crystalline graphite and amorphous carbon (a-C) phases.
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6 Notably, improved tribological properties of crystalline diamond, including UNCD and
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8 diamond-like carbon (DLC) films are generally explained by two existing mechanisms i.e.
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10 passivation and graphitization of the sliding interfaces.^{5,6,12,15-21} In the passivation mechanism,
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12 the film surface being chemically inert is not much deformed which provides mechanical
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14 stability. In contrast, the transformation of sp^3 crystalline diamond into sp^2 and a-C phases is
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16 responsible for damage and deformation of the sliding interfaces.^{6,12,18} Several aspects including
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18 the internal chemical structure of films and tribo-test environment are governing factors for
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20 determining passivation and/or graphitization mechanisms. However, these important aspects are
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22 not yet quantitatively understood in the controlled atmosphere and high-temperature tribo-
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24 condition in order to relate with friction and wear properties of the films.
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31 Tribological properties of UNCD films show the strong dependence on humidity, gaseous
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33 environment and vacuum tribo-condition.^{16,22} At high humidity, the film showed ultralow
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35 friction coefficient and high wear resistance and this was associated to the passivation of
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37 dangling bonds of the sliding interfaces.^{16,22} Moreover, Maria-Isabel *et al.* showed ultralow
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39 friction of nanocrystalline (NCD) films in water vapor medium which is associated with the OH
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41 and H passivation of the sliding surfaces.²³ Such improved properties of these films were
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43 obtained even in dry environments where negligible rehybridization was observed and the low
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45 friction behavior was supported by passivation mechanism.^{16,23} In another study, low friction was
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47 measured in low humidity (5%) condition and was understood due to graphitization of the sliding
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49 interfaces.²⁴ Konicek *et al.* described that even low humidity is sufficient to passivate the
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graphitized sliding interfaces.¹⁶ Passivation mechanism of diamond surface was well described by adsorption-dissociation of water molecules.²⁵

Interestingly, the friction coefficient was lower in more graphitized grain boundaries of UNCD films which was explained by the low shear resistance induced sliding mechanism between the graphitic sheets.^{11,12,26} Even under mild tribological conditions, tribo-induced sp^3 to sp^2 hybridization was detected at the surface of wear track resulting in the formation of thin amorphous sp^2 -rich carbon layer embedded with ultranano diamond grains.¹⁵ Moreover, Bouchet *et al* described that the graphitization and passivation are together an effective mechanism for low friction and wear.¹⁵ Passivation is essential even for sp^2 -tribo-induced phase which is a by-product of sp^3 -hybridized carbon, yielding low friction. The tribo-induced transformation from tetrahedral amorphous carbon (t-aC) and UNCD films to a-C and sp^2 phase was experimentally observed by X-ray absorption near-edge fine structure technique and theoretically simulated by molecular dynamics (MD).²⁷ Zhang *et al.* observed such transformation in microcrystalline coarse grain diamond films in nitrogen atmosphere by Raman spectroscopy, resulting in low friction coefficient of 0.15.²⁸ Furthermore, tribo-induced phase transformation in single crystal diamond, yielding sp^2 -hybridised amorphous layer was studied by MD simulations.²⁹ The sp^2 carbon phase in diamond and DLC films is more active in high temperature tribo-condition. Therefore, the improvement in tribological properties of these films are challenging mainly due to transformation possibility of carbon phases at high temperature. At elevated temperatures and in ambient atmosphere condition, the DLC films undergo gradual transformation from a highly disordered or amorphous state to an increasingly ordered or graphitic state.^{30,31} This is associated to thermodynamically unstable phase of DLC films. Therefore, friction and wear behaviors of DLC films are unstable and change with change in their chemical and structural properties at

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3 higher temperatures. The hydrogenated DLC films may provide low friction up to 300°C for
4 shorter sliding cycles, but during repeated sliding process, these films tend to wear faster.³⁰
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6 However, DLC films with hydrogen-free ta-C phase may last longer. Moreover, friction
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8 coefficient of these films tend to increase with increasing test temperature due to thermal
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10 desorption of water and other adsorbed species. Li *et al.* have shown that the friction coefficient
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12 and wear rate of thermally annealed polycrystalline diamond films were reduced due to
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14 formation of the carbonaceous transfer films.³² Shabani *et al.* have investigated the high friction
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16 value of multilayer micro/nanocrystalline diamond films at elevated temperature due to dry
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18 contact condition.³³ However, ultralow friction coefficient in polycrystalline diamond films was
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20 measured at moderate temperature in oxygen atmosphere.³⁴ This was ascribed to the chemically
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22 stable adsorbed oxygen moiety formation on the film surface that saturates carbon dangling
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24 bonds of diamond films.^{35,36} Moreover, shear-induced graphitization of the sliding interfaces
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26 may possibly explain the low friction in polycrystalline diamond films.^{35,37} In high vacuum
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28 conditions, graphitization and amorphization of diamond films are substantial which has an
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30 adverse effect on friction and wear response. This can be explained by the lack of external
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32 passivation when chemical adsorbate is absent to passivate the unsaturated bonds at sliding
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34 interfaces.^{38,39} However, hydrogenated UNCD films show low/ultralow friction value in high
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36 vacuum condition due to passivation mechanism.^{26,40} This was performed by hydrogen
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38 atoms/molecules intrinsically present in the films. Moreover, at moderate temperature, surface
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40 graphitization of diamond films was favorable in reducing the friction in air and vacuum
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42 conditions.^{41,42} Furthermore, ultra-low friction coefficient with high wear resistance was
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44 measured at 200°C in UNCD films and this was explained by the formation of chemically
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46 passivated sliding interfaces. However, at higher temperature, tribological performance of these
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3 films were significantly degraded and failure happened mainly due to oxidation and
4 amorphization/polymerization of the sliding interfaces.⁴³ Therefore, passivation of dangling
5 bonds and conversion of sp^3 into sp^2 and a-C mainly depend on the temperature and
6 environmental conditions. However, it is quite difficult to understand the suitable mechanism of
7 friction and wear behavior in high-vacuum and high-temperature tribo-conditions without
8 substantial characterization of tribofilm which was produced at sliding interfaces. Sustainable
9 performance of materials in above mentioned tribo-conditions is useful for high temperature and
10 space applications. However, tuning the tribo-sustainable properties of thin films via tailoring
11 morphology, chemical composition and microstructure is a challenging task.

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24 Here, we report the deposition of tribologically novel and sustainable UNCD nanowall
25 (NW) thin films using microwave chemical vapor deposition system employing the unique
26 plasma conditions. To elucidate the comprehensive tribological properties, the test of UNCD
27 NW films were conducted in the controlled tribo-environmental conditions such as ambient
28 atmosphere and room temperature (AA-RT), high-vacuum and room temperature (HV-RT) and
29 high-vacuum high-temperature (HV-HT). In order to explain the distinct underlying tribo-
30 mechanisms, these tribo-atmospheres were used to manipulate the chemical nature of contact
31 interfaces. The change in the chemical structure of tribo-interfaces was characterized by Raman
32 spectroscopy and X-ray photoelectron spectroscopy with micrometer spatial resolution.
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Chemical modification of carbonaceous tribofilm at contact interfaces in three different tribo-
conditions was quantitatively explained by shear induced amorphization/graphitization and
passivation mechanisms. Moreover, friction and wear behavior was explained based on the
chemical structure of tribofilms at the sliding interfaces.

2. EXPERIMENTAL SECTION

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3 **2.1. Film Deposition.** UNCD nanowalls films were deposited on (100) oriented silicon substrate
4 using microwave plasma enhanced chemical vapor deposition (MWPECVD; SEKI Technotron
5 AX5400S, Japan) system. The base pressure inside the chamber was 10^{-4} Torr. Prior to diamond
6 growth, the silicon substrate was seeded by spin-coating in the diamond slurry.⁴⁴ The nanowalls
7 have been fabricated using the following process conditions: gas mixtures of CH₄, H₂ and N₂
8 with a total flow rate of 328 sccm, microwave power of 1300 W, the process pressure of 50 Torr,
9 and microwave radiation frequency of 2.45 GHz. During the deposition process, the substrate
10 holder was heated up to 700°C by an induction heater, which was controlled by a thermocouple.
11 The deposition parameters of these films differ from earlier UNCD nanowire films deposited in
12 CH₄/N₂ plasma condition without the addition of H₂.^{11,12}
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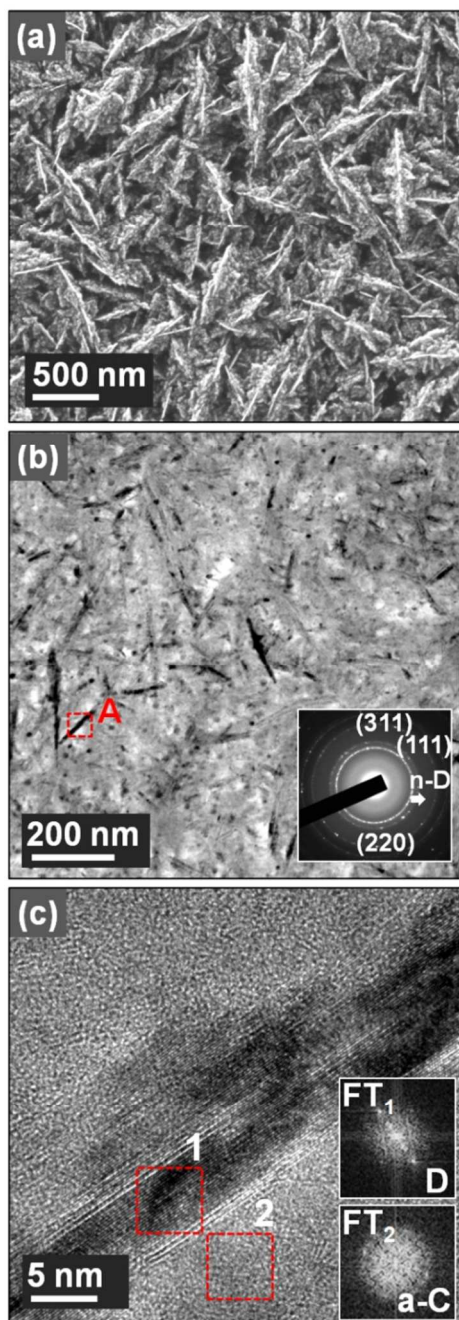
26 **2.2. Characterization Techniques.** Morphology of these films was characterized by field
27 emission scanning electron microscopy (FESEM, Zeiss Supra 55). High-resolution
28 microstructure and crystallographic investigation of UNCD nanowall films were examined by
29 transmission electron microscopy (TEM; JOEL 2100). Bonding structure of films surface, wear
30 tracks and ball scars were studied by micro-Raman spectrometer (Andor SR-500i-C-R,
31 wavelength 532 nm). Chemical bonding of films surface, wear tracks and ball scars were
32 characterized by energy dispersive X-ray spectroscopy (EDS). Wide range survey and high-
33 resolution X-ray photoelectron spectroscopy (XPS) of films and mechanochemically modified
34 contact interfaces were recorded by Sigma probe-Thermo VG Scientific equipped with
35 hemispherical analyzer and micro-focused monochromator X-ray source with spatial resolution
36 of 50 μm. The XPS analysis was carried out using Al Kα radiation (E=1486.6 eV) with an
37 energy resolution of 0.47 eV in ultra-high vacuum at 10^{-10} Torr.
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3 **2.3. Tribology Tests Condition.** Friction and wear behaviors of UNCD NW films were studied
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5 by ball-on-disc high-vacuum high-temperature tribometer (HV-HT Anton Paar, Switzerland)
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7 operating in a circular motion mode. For friction measurements; normal load, sliding speed and
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9 diameter of sliding contact were 0.5 N, 50 rpm and 5 mm, respectively. Alumina (Al_2O_3) ball
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11 with 6 mm diameter was used as a sliding counterbody. The hardness of Al_2O_3 ball is 12 GPa
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13 and average roughness of 45 nm. The above values were standardized and provided by the
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15 supplier (HV-HT Anton Paar, Switzerland). The tribo-tests were conducted in three different
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17 atmospheres: (a) AA-RT with ambient atmosphere and room temperature (b) HV-RT with
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19 vacuum level $\sim 5 \times 10^{-6}$ mbar and room temperature (c) HV-HT with vacuum level $\sim 5 \times 10^{-6}$ mbar
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21 and film temperature ~ 623 K. Two dimensional (2D) wear profile was measured by Dektak 6M-
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23 stylus profiler for the wear analysis.
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30 **3. RESULTS AND DISCUSSION**

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32 **3.1. Morphology and Microstructure.** SEM micrographs shown in [Figure 1a](#) indicated that
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34 UNCD NW films shows predominantly nanowall-like feature with the size of 200 to 300 nm in
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36 length. These features are homogeneously distributed all over the film surface. [Figure 1b](#) shows
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38 the bright field TEM (BF-TEM) micrograph of UNCD NWs, revealing the unique granular
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40 structure of these films. The UNCD NW films consist of needle-like clusters of hundreds of
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42 nanometers in length. The selected area diffraction (SAED) pattern showed (111), (220), and
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44 (311) rings of diamond plane and a central diffuse ring of sp^2 -bonded carbon (nanographite or a-
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46 C phase) or *trans*-polyacetylene (TPA) located in the grain boundaries. The presence of
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48 diffraction rings implies that the needle-like clusters are predominantly diamond and the
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50 diamond grains are randomly oriented, whereas the central diffuse ring is presumably
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3 contributed from the sp^2 -bonded carbons associated with the needle-like clusters. This is
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5 illustrated in the high-resolution TEM micrograph in more detailed (Figure 1c).
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50 **Figure 1.** (a) SEM image of UNCD NW films surface, (b) typical TEM bright field (BF)
51 micrograph with corresponding selective area electron diffraction (SAED) pattern shown as
52 inset and (c) HRTEM image corresponding to the marked region “A” of Figure 1(b) of UNCD
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3 *NWs. The insets FT₁ and FT₂ of figure 1(c) show the Fourier-transformed (FT) diffractogram*
4 *images corresponding to regions 1 and 2, respectively.*
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8 The needle-like clusters contain diamond about 5 nm in width and hundreds of nanometers in
9 length as core and sp²-bonded carbon (nanographite or amorphous carbon) as shell. The FT₁ and
10 FT₂ Fourier-transformed diffractogram further confirmed that the core and shell consists of
11 diamond and sp²- bonded carbon, respectively. There exists an extra ring with smaller size than
12 (111) ring (indicated by the arrow in inset of Figure 1b), which corresponds to *n*-diamond (*n*-D),
13 a metastable form of diamond with FCC structure and cell parameter of 0.356 nm.^{45,46} It is worth
14 mentioning that the morphology and microstructure of the present films differ significantly from
15 our published results and this fact is related to altered plasma condition during deposition
16 process.^{11,12} Here, UNCD NW exists in nanowall feature embedded with a-C structure. However,
17 in earlier work, nanowire like feature was formed.^{11,12}
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31 **3.2. Bonding Structure of Bulk and Surface of Films.** The bonding structure of bulk and
32 surface of films were comprehensively investigated by Raman spectroscopy and XPS analyses
33 and the results are shown in Figure 2. Raman spectra showed four deconvoluted peaks
34 designated by ν_1 (1168 cm⁻¹), ν_3 (1510 cm⁻¹), D (1329 cm⁻¹) and G (1582 cm⁻¹) bands which are
35 the nondiamond phases existing in the grain boundaries⁴⁷ (Figure 2a). The ν_1 and ν_3 correspond
36 to TPA phases^{48,49} and the other two D and G bands with I(D)/I(G) ratio of 1.65 shows the
37 signature of a-C and graphite phases.⁵⁰ Fundamental phonon band of diamond in UNCD is not
38 observable mainly for two reasons: (a) broadening effect due to phonon confinement in ultranano
39 grains and (b) quenching of diamond band due to appearance of broad nondiamond D band at
40 similar Raman shift. Such a Raman characteristic is a signature of UNCD films.^{11,51} More
41 detailed surface bonding characteristics was investigated by XPS (Figure 2b-d). Survey spectra
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in Figure 2b showed photoelectron emission of carbon (C1s) and oxygen (O1s) at 285.5 and 531.1 eV,⁵² respectively, of UNCD NW film and C/O ratio is 2.92. A small fraction of oxygen at films surface is associated to the contamination due to exposure in ambient environment. Moreover, Auger photoelectron shift of these elements as OKLL and CKLL are also observed. Another weak chemical shift of N1s photoelectron was observed at 399.32 eV which signifies the impurities associated to nitrogen gas in plasma medium used for the deposition of UNCD NW films. X-ray photoelectron emission of Si2p and Si2s lines, related to the silicon substrate, were also observed in trace level as impurities.

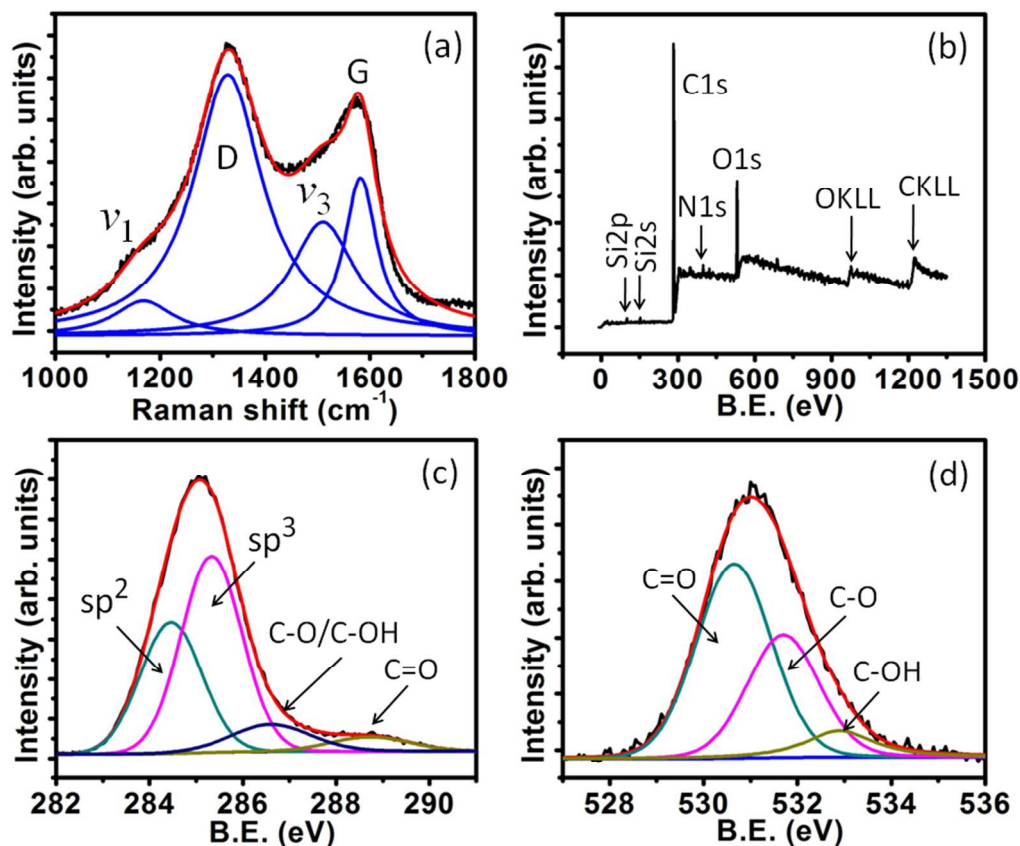


Figure 2. (a) Raman spectra and (b-d) XPS spectra of UNCD NW film surface: (b) survey spectra and high-resolution XPS: (c) C1s and (d) O1s X-ray photoelectron emission lines.

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3 High-resolution (HR) XPS of photoelectron emission bands of C1s and O1s are plotted in
4 [Figure 2c](#) and [2d](#), respectively. A broad C1s photoelectron emission spectrum is deconvoluted
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6 into four peaks at the binding energies of 284.46, 285.3, 286.6 and 288.7 eV. The background
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8 was subtracted following the Shirley method.⁵³ The first two peaks are designated as sp^2 and sp^3
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10 hybridized carbon and third and fourth peaks correspond to oxygen functional groups such as the
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12 carboxylic (C-O/C-OH) and carbonyl (C=O) groups, respectively.^{22,54,55} The ratio of sp^3/sp^2
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14 phase is 1.48 and energy width of photoelectron emission for sp^2 and sp^3 peaks are equivalent to
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16 1.55 and 1.54 eV, respectively. These films showed the large fraction of sp^2 carbon phase as
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18 compared to earlier reported work^{11,12} and therefore, chemical properties of these UNCD NW
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20 films are distinctly different and novel for tribological applications. Moreover, deconvolution of
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22 broad O1s peak results in three photoelectron emission lines centered at binding energies of
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24 530.65, 531.7 and 532.9 eV that correspond to the C=O, C-O and C-OH functional groups,
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26 respectively.^{22,56} These groups are attainable due to the surface contamination and adsorption of
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28 atmospheric moisture and water vapor molecules.
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35 **3.3. Friction and Wear Characteristics.** Friction and wear behavior of UNCD NW films
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37 distinctly differ depending upon their tribo-test environments ([Figure 3](#)). Two separate
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39 measurements for each tribo-condition were carried out and in each condition, the measurement
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41 was found to be reproducible. The saturated value of friction coefficient in AA-RT was ~ 0.023
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43 (curve a_1) which significantly increased to ~ 0.17 in HV-RT tribo-condition (curve a_2) and in
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45 addition, early film failure was also noticed. However, the friction value was decreased to ~ 0.002
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47 in HV-HT tribo-condition (curve a_3). Raw data of friction curves in all three different
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49 atmospheres are presented in Supplementary Information ([Figure S1](#)). Wear dimension is found
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to be directly proportional to the friction value and it is lowest in HV-HT as compared to other two conditions (Figure 3d).

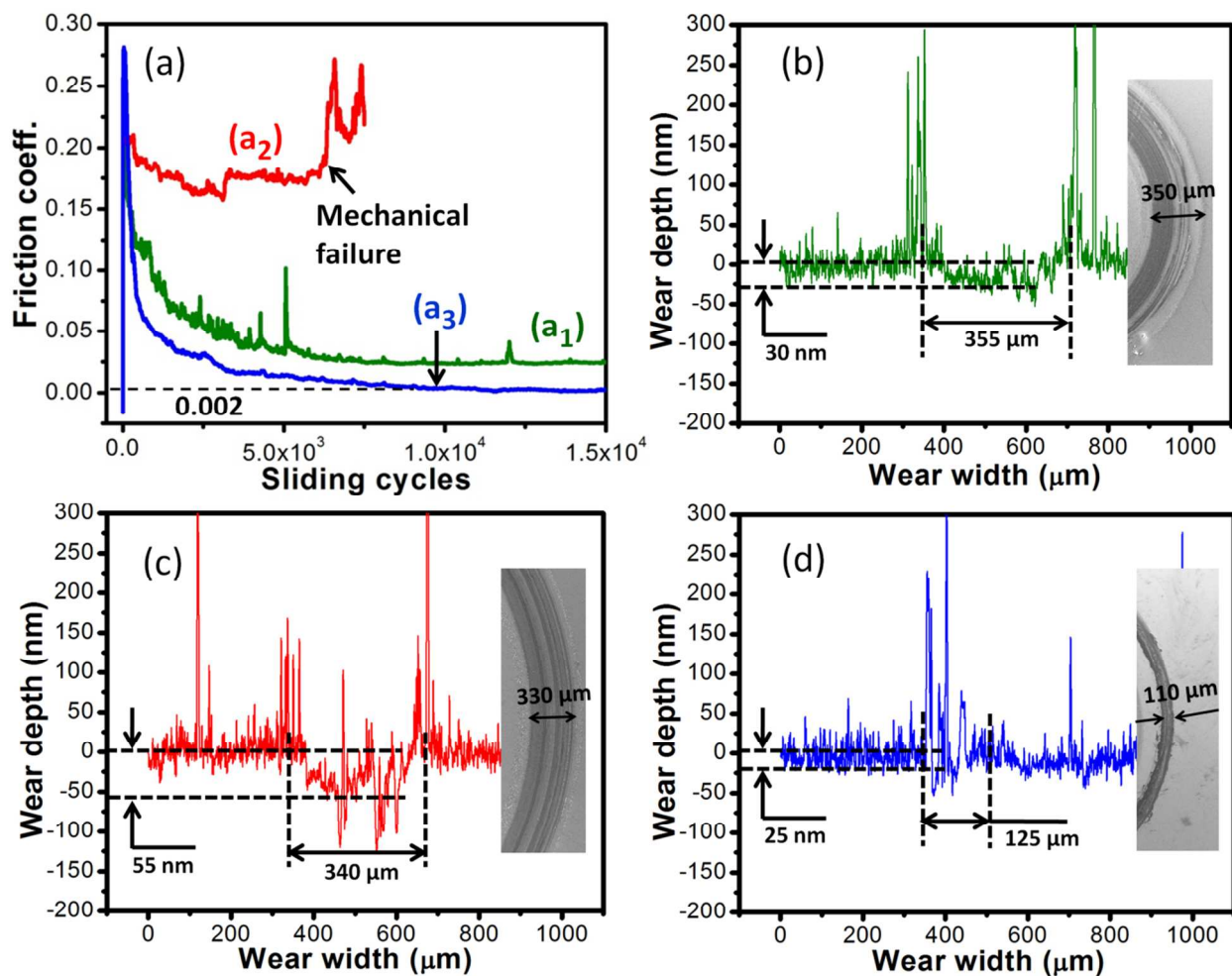


Figure 3. (a) Friction coefficient vs sliding cycles of UNCD NW film: (a₁) AA-RT (a₂) HV-RT and (a₃) HV-HT tribo-condition, and 2D wear track profile in (b) AA-RT (c) HV-RT and (d) HV-HT tribo-condition. SEM images of the corresponding wear tracks are embedded for each condition; tribology parameters: load: 0.5 N, speed: 50 rpm, ball: Al₂O₃ (dia. 6 mm).

Four wear profile measurements were performed for each wear track at random locations and the data were quite repeatable. Wear dimension evidence is well supported by the low-resolution

SEM images embedded in [Figure 3b-d](#). Moreover, high-resolution SEM images of wear track formed in AA-RT condition showed that the nanostructure feature of UNCD NW films was sustained without much deformation ([Figure S2](#)). However, plastically deformed nanostructured morphology of UNCD NW in the wear track was observed in HV-RT tribo-condition ([Figure S3](#)). In this case, the wear dimension and extent of deformation of the ball is much higher compared to AA-RT condition. Contrasting SEM image of the wear track formed in HV-HT was observed with transformation of the UNCD NW morphology into layered deformed patches ([Figure S4](#)). Furthermore, in this case, deformation of ball and wear track dimensions much less. It is worth mentioning that in HV-HT condition, films were highly wear resistant with wear loss of 0.0016 nm/cycles. However, wear loss of films in AA-RT and HV-RT tribo-condition was 0.002 nm/cycles and 0.006 nm/cycles, respectively. It shows that the wear resistance of the films in HV-HT was improved up to 17% and 55% as compared to AA-RT and HV-RT tribo-condition, respectively. Tribological properties of UNCD nanowire films were studied earlier by our group in ambient atmosphere and room temperature condition.^{11,12} However, in this present study, the value of friction coefficient of UNCD NW films is lower than UNCD nanowire films. Moreover, friction value of UNCD NW films is almost vanishing to the value of 0.002 with negligible wear loss in HV-HT condition. This value is much less compared to earlier reported work.^{11,12,16,22-24} To the best of our knowledge, this is a first tribological measurement on UNCD NW films conducted in three different controlled environments for comparative studies. Moreover, in-depth chemical characterizations of sliding interfaces were performed comprehensively to understand the governing friction and wear mechanisms. These are discussed in the following sections.

4. CHEMICAL COMPOSITION AND PHASE ANALYSIS OF SLIDING INTERFACES

4.1. EDS Analysis of Sliding Interfaces. EDS analysis was carried out for qualitative elemental analysis of wear product and chemical composition of tribo-contact interfaces in three different tribological conditions. The results are presented in [Figure S5-7](#). Wear track analysis showed the localized patch formation of O and Al entities as shown in the micrograph in AA-RT tribo-condition ([Figure S5a](#)). A typical patch designated as (a₂) and corresponding spectra (b₂) is shown in [Figure S5b](#). These elements are wear product of Al₂O₃ ball which is formed due to deformation in AA-RT tribo-condition. However, whole area mapping denoted by (a₁) does not show the significant quantity of O and Al in spectra (b₁), indirectly indicating the localized formation of Al₂O₃ as a wear product. Here, the contribution of atmospheric oxygen along with oxygen from Al₂O₃ is worth to mention. In the similar tribo-condition, ball contact showed the signature of C and this is a product of transferlayer from UNCD film onto Al₂O₃ ball sliding contact. These are indicated in EDS mapping spots of (c₁-c₃) in [Figure S5c](#) and corresponding spectra in (d₁-d₃) in [Figure S5d](#). Atomic fraction of deformed wear product of Al₂O₃ ball was negligible in the wear track of HV-RT tribo-condition ([Figure S6a](#)). Therefore, the EDS spectra of the whole region (a) showed the negligible atomic fraction of Al and O and in this particular environment, the oxidation was also restricted due to the high vacuum condition ([Figure S6b](#)). However, bulk quantities of these elements present at the ball scar is an indication of Al₂O₃ ball ([Figure S6d](#)). More importantly, the X-ray signal of C is strong at the ball scar and this indicates the formation of transferfilm. The location at ball scar for EDS analysis is indicated in [Figure S6c](#). The negligible fraction of Al and O was observed at the wear track of UNCD films in HV-HT tribology condition. The EDS mapping spots are shown as (a₁-a₂) in [Figure S7a](#) and corresponding spectra are presented in (b₁-b₂) of [Figure S7b](#), respectively. More importantly, in

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3 this case, the atomic fraction of C is high at the ball scar due to transferfilm formation. This is
4 shown in spots (c₁-c₂) in [Figure S7c](#), and corresponding spectra in (d₁-d₂) in [Figure S7d](#).
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7 Qualitatively, it is concluded that carbon transferfilm is present on ball scar in all the three tribo-
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9 conditions. Atomic percentage of carbon is large in HV-RT and HV-HT tribology conditions
10 compared to AA-RT. However, EDS technique being bulk sensitive is not sufficient to
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12 investigate the chemical phase composition of carbon at sliding interfaces. Therefore, the
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14 combination of spatially resolved Raman and XPS techniques were used for in-depth chemical
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16 phase composition analysis of sliding interfaces in three different tribo-conditions. These are
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18 discussed in the following sections.
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24 **4.2. Raman Spectroscopy of Sliding Interfaces.** Wide frequency range of raw Raman spectra
25 and the corresponding deconvoluted spectra of UNCD NW films in the specific range for AA-
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27 RT tribo-condition are shown in [Figure 4a](#) and [4b](#), respectively. For comparison purpose, all the
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29 parameters of Raman spectrometer were kept similar. The Raman spectrum of the film surface is
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31 also presented for reference purpose.
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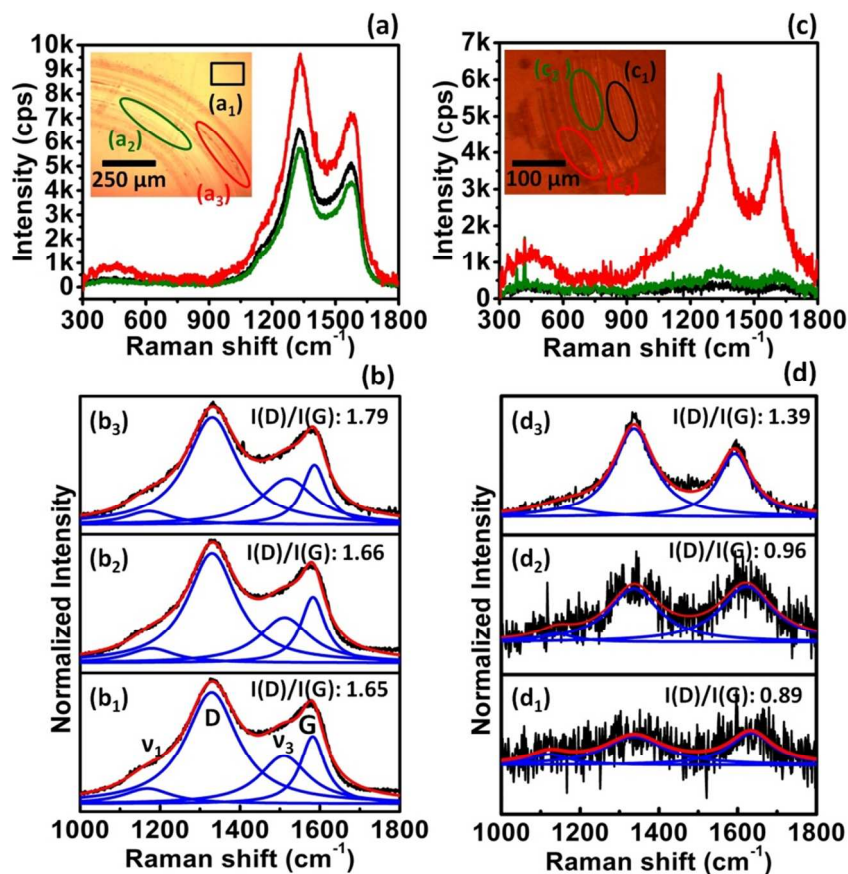


Figure 4. (a and b): Raw data of Raman spectra of film surface (a_1) and inside the wear track (a_2)&(a_3) and corresponding deconvoluted spectra (b_1 - b_3), respectively; (c and d): raw data of Raman spectra at ball scars (c_1 - c_3) and deconvoluted spectra (d_1 - d_3), respectively; tribology parameters: load: 0.5 N, speed: 50 rpm, ball: Al_2O_3 (dia. 6 mm), condition: ambient and room temperature (AA-RT).

Chemical structure of the UNCD NW wear track is stable and does not show the large difference in I(D)/I(G) value (Figure 4b). This ratio is an important parameter for the determination of the chemical structure of carbon phase.⁵⁰ However, the marginal increase in this ratio locally inside the wear track signifies slight enhancement in a-C/sp² phase. This change clearly showed the increase in intensity counts in (a_3) of Figure 4a. Moreover, D and G peak position inside the wear track is quite similar to the film surface. There is not much change in TPA phase inside the wear track and this fact directly points towards the stable UNCD structure in AA-RT tribo-condition.

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3 Chemical stability of this structure can be explained by passivation of sliding interfaces through
4 ambient atmospheric chemical species. Similar Raman shift at the ball scar clearly indicates the
5 formation of carbonaceous film (Figure 4c). However, peak shape, intensity and peak position of
6 tribofilm locally differs at the ball scar which is an indication of heterogeneous carbonaceous
7 transferfilm formation. This is shown in deconvoluted spectra (d_1 - d_3) of Figure 4d. Moreover,
8 $I(D)/I(G)$ value is less and the blue shift in D and G bands is noticed at the ball scar compared to
9 wear track. This is a direct indication of shear induced a-C to graphitization in the ambient
10 atmospheric condition.⁵⁷ This may also be confirmed by the weakness of TPA phase due to the
11 chemical modification of UNCD structure. Further, the altered shape of the Raman bands with
12 the decrease in $I(D)/I(G)$ value in the range of 0.9 to 1 was observed at most of the places of ball
13 scar. However, locally this value was reached to 1.4 which showed stable tribofilm formation of
14 chemically modified UNCD NW phase at the ball scar.

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31 UNCD structure of wear track in the HV-RT tribo-condition is also stable and the Raman
32 bands are more or less comparable to virgin UNCD film surface. The results of Raman spectra of
33 wear track in HV-RT tribo-condition are shown in Figure 5a-b.
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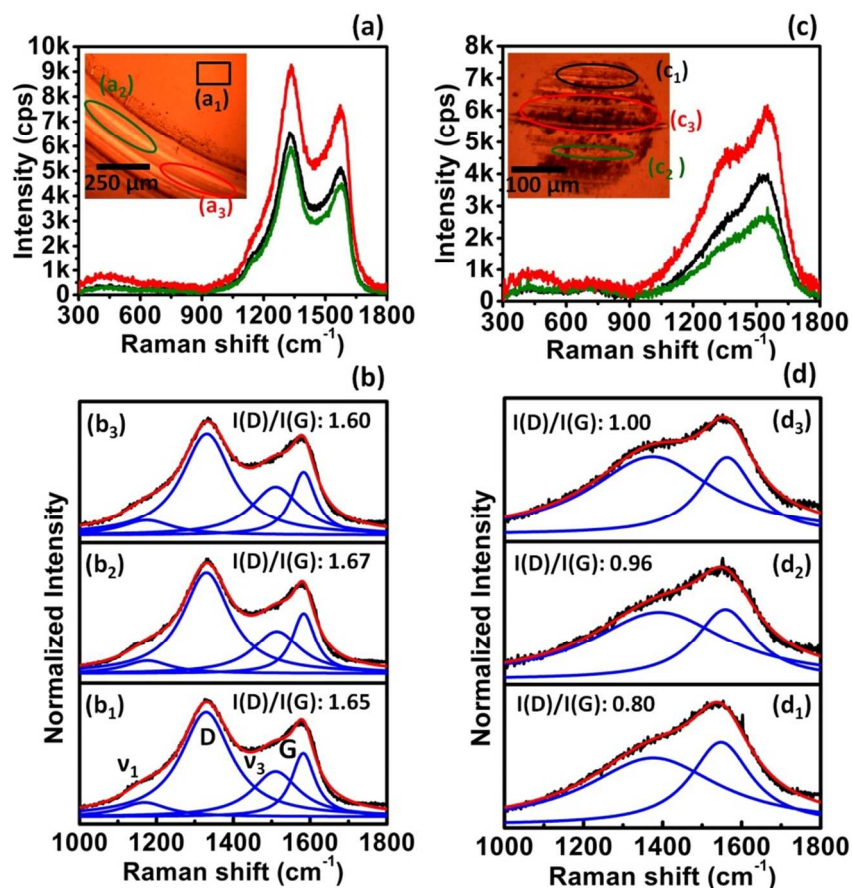
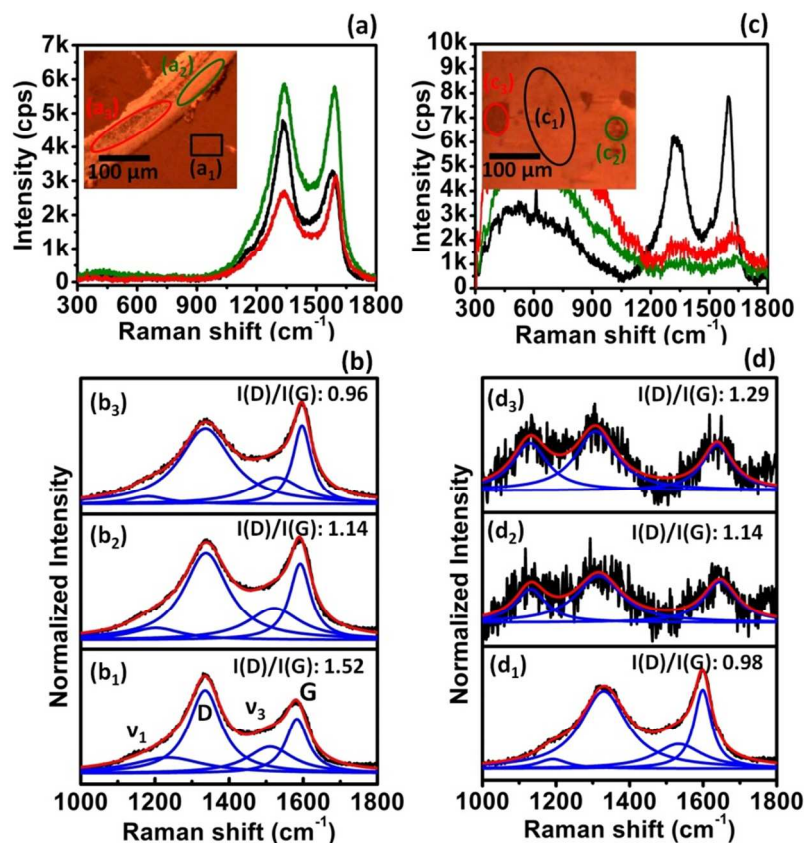


Figure 5. (a and b): Raw data of Raman spectra of film surface (a_1) and inside the wear track (a_2)&(a_3) and corresponding deconvoluted spectra (b_1 - b_3), respectively; (c and d): raw data of Raman spectra at ball scars (c_1 - c_3) and deconvoluted spectra (d_1 - d_3), respectively; tribology parameters: load: 0.5 N, speed: 50 rpm, ball: Al_2O_3 (dia. 6 mm), condition: high-vacuum (5×10^{-6} mbar) and room temperature (HV-RT).

In this HV-RT condition, Raman peak parameters such as peak shape, peak position, I(D)/I(G) value and TPA phase of UNCD in wear track are quite similar to the wear track formed in AA-RT tribo-condition. However, the chemical structure of carbonaceous tribofilm formed at the ball scar is completely transformed into a-C and t-aC structure.⁵⁸ This is noticed by the significant change of peak shape, peak position and modified value of I(D)/I(G) ratio as shown in (d_1 - d_3) of Figure 5d. In this condition, the blue shift in D and red shift in G bands was observed as

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3 compared to carbon structure of wear track. Here, TPA phase is completely disappeared and this
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5 could be a strong indication for the conversion of UNCD into a-C and t-aC structure. This could
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7 be possible due to the high frictional energy which acts as activation energy for such
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9 transformation. Therefore, in case of HV-RT, the ball scar is fully covered by bulk tribofilm of a-
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11 C and t-aC phases. Thus, in this particular condition, sliding occurred between UNCD NW film
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13 and a-C/t-aC structure on ball side.
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17 Distinct changes in Raman spectra of the sliding interfaces in HV-HT tribology condition
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19 were noticed as shown in Figure 6a-d. Here, $I(D)/I(G)$ value of film surface is 1.52 as shown in
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21 (a₁) of Figure 6a. This value is less compared to the ambient UNCD film as shown earlier in
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23 Figure 2a and (a₁) of Figure 4a.
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53 **Figure 6.** (a and b): Raw data of Raman spectra of film surface (a₁) and inside the wear track
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55 (a₂)&(a₃) and corresponding deconvoluted spectra (b₁-b₃), respectively; (c and d): raw data of
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3 *Raman spectra at ball scars (c₁-c₃) and deconvoluted spectra (d₁-d₃), respectively; tribology*
4 *parameters: load: 0.5 N, speed: 50 rpm, ball: Al₂O₃ (dia. 6 mm), condition: high-vacuum (5 × 10⁶*
5 *mbar) and high-temperature (623 K) (HV-HT).*
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10 Moreover, at high vacuum high-temperature condition, the D and G bands are blue shifted
11 indicating temperature induced annealing which tends to reorient the carbon structure into more
12 ordered sp² phase. However, I(D)/I(G) ratio is significantly decreased in the wear track as
13 compared to the film surface as shown in (b₂-b₃), [Figure 6b](#). For better quantitative analysis,
14 Raman spectra are obtained at several locations of wear track in all three different tribology
15 conditions ([Figure S8](#)). The Raman analysis showed the shift of D and G bands to higher
16 wavenumber and decrease in I(D)/I(G) ratio in HV-HT condition. This behavior describes bulk
17 graphitization of the contact surface⁵⁷ and it is contrasting to the wear track formed in AA-RT
18 and HV-RT tribo-condition as mentioned above. This indicates that the contact pressure at high
19 temperature in high vacuum tribo-condition is a deterministic factor to reorient the disordered sp²
20 into more ordered sp² phase. Moreover, conversion of sp³ to sp² phase is also possible and it
21 depends on the activation energy which is gained by the temperature and contact pressure. Most
22 portion of the ball scar is covered by graphitized transfer film where I(D)/I(G) ratio is 0.98 as
23 shown in (d₁) of [Figure 6d](#). However, graphitized tribofilm is highly distorted at few localized
24 positions of the ball scar (d₂-d₃) in [Figure 6d](#). This is confirmed by the distinct shape of Raman
25 bands with the increase in I(D)/I(G) value. Here, raw data of (c₂-c₃) in [Figure 6c](#) showed very
26 weak intensity of D and G bands which indicates the thin layer of distorted carbon structure. It is
27 worth mentioning that Raman spectroscopy is a bulk sensitive technique and therefore, formation
28 of such above mentioned phases is a bulk phenomenon. This was earlier reported by Bouchet *et*
29 *al.* which showed formation of 40 nm thick sp² rich carbon layer at the top of coating.¹⁵ The sp²
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3 hybridization change of sliding DLC surfaces under ultralow friction regime was also observed
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5 for amorphous ta-C films with even larger thickness of 50 nm.⁵⁹
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8 **3. X-ray Photoelectron Spectroscopy of Ball Scar.** XPS was used for more insightful surface
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10 chemical analysis of tribofilm deposited on the ball contact region during the sliding process.
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12 This is an essential tool for understanding the friction behavior in three different tribo-conditions.
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14 The spatial resolution of XPS was 50 μm and therefore, it was possible to focus the X-ray at
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16 specific locations inside the wear scar region of the ball surface. For this purpose, mainly
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18 deformed and less deformed regions were selected at each ball scar for quantitative chemical
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20 analysis. It is worth mentioning that these selected regions are representative of full scar. The
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22 common spots for Raman and XPS were located for comparative chemical analysis. Survey XPS
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24 showed well resolved C1s and O1s photoelectron shift obtained from the ball scar region in three
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26 different tribo-conditions such as AA-RT, HV-RT and HV-HT. These spectra are shown in
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28 [Figure 7-9b](#) and the corresponding physical locations of spectra are indicated in optical images in
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30 [Figure 7-9a](#), respectively. These results show the carbonaceous tribofilm formation at the Al_2O_3
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32 ball with adsorbed oxygen content. Survey spectra showed that in AA-RT tribo-condition, C/O
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34 ratio is less at the deformed region (0.51) as compared to the plain/less deformed region (0.68)
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36 and intensity of the alumina peaks ($\text{Al}2\text{p}$ and $\text{Al}2\text{s}$) is strong in deformed region ([Figure 7b](#)).
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38 These regions are located as (a_1) and (a_2) in [Figure 7a](#).
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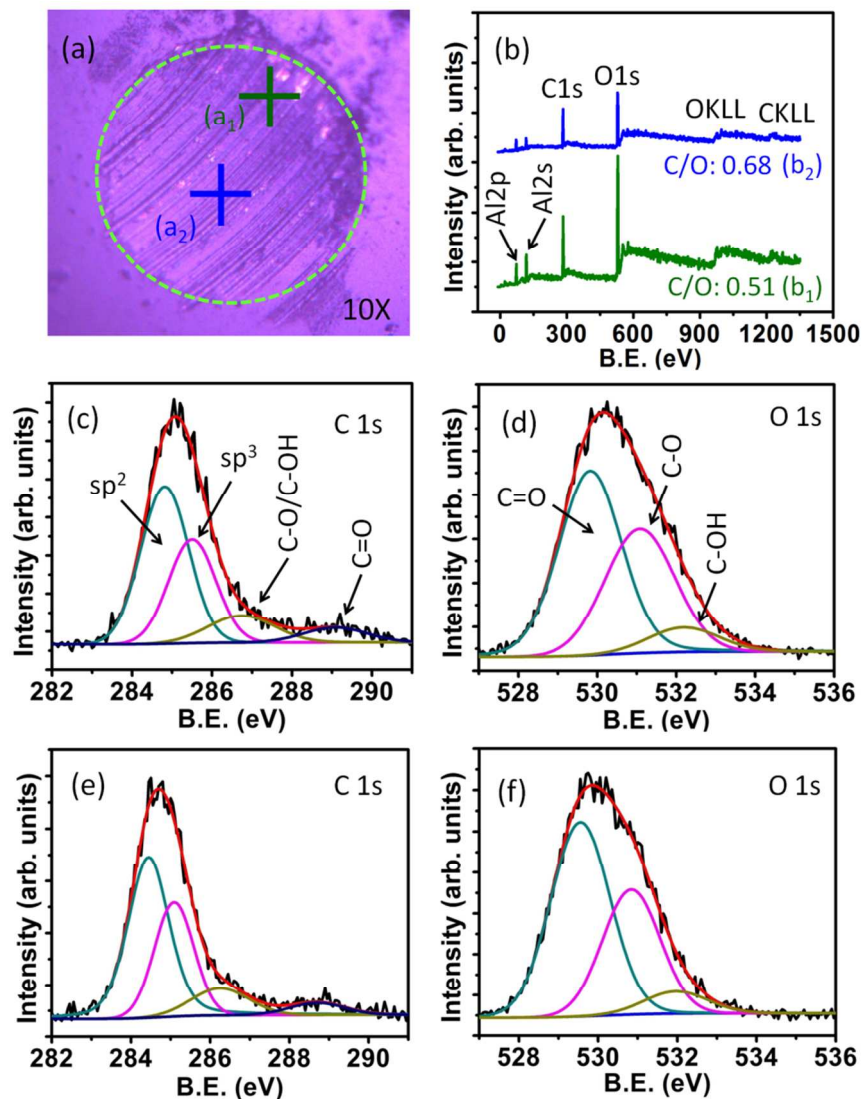


Figure 7. (a) Optical image of ball scar in AA-RT tribo-condition: (a₁) deformed and (a₂) less deformed region and corresponding survey XPS spectra of (b₁) and (b₂), respectively; HR-XPS of C1s and O1s of (c and d) deformed and (e and f) less deformed region, respectively.

This indicates the excess exposure of alumina at the deformed region. Here, C/O ratio is much lower as compared to the virgin film surface due to tribo-induced adsorption of oxygen (Figure 2b). The effective adsorption of oxygen is associated to the high energy of deformed Al₂O₃ ball surface which further react with the water vapor, forming adsorbed oxygen contamination. HR-XPS of C1s photoelectron shift obtained from both the locations i.e. deformed and less deformed

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3 regions showed well-resolved deconvoluted sp^3 and sp^2 peaks with the contribution of oxygen
4 functional groups. These are represented in [Figure 7c](#) and [7e](#), respectively. The sp^3/sp^2 ratio in
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6 deformed and less deformed region is 0.65 and 0.6, respectively. These values are much lower as
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8 compared to virgin film surface ([Figure 2c](#)) and it is an indicative of tribo-chemical conversion
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10 of sp^3 to sp^2 phase. In these regions, HR-XPS of O1s photoelectron shift showed well-resolved
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12 oxygen functional groups⁵² ([Figure 7d](#) and [7f](#)) and spectral characteristics are similar to virgin
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14 film surface ([Figure 2d](#)). This indicates that the chemical environment of functional groups does
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16 not depend much on deformation of Al_2O_3 ball surface. In contrast, adsorption of oxygen
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18 quantity directly depends on the deformation which is related to the change in surface energy.
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24 Survey spectra showed C/O ratio of 0.68 and 0.48 at two different locations of the scar
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26 formed in HV-RT tribo-condition ([Figure 8b](#)). These regions are located in (a₁) and (a₂) of [Figure](#)
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28 [8a](#), respectively.
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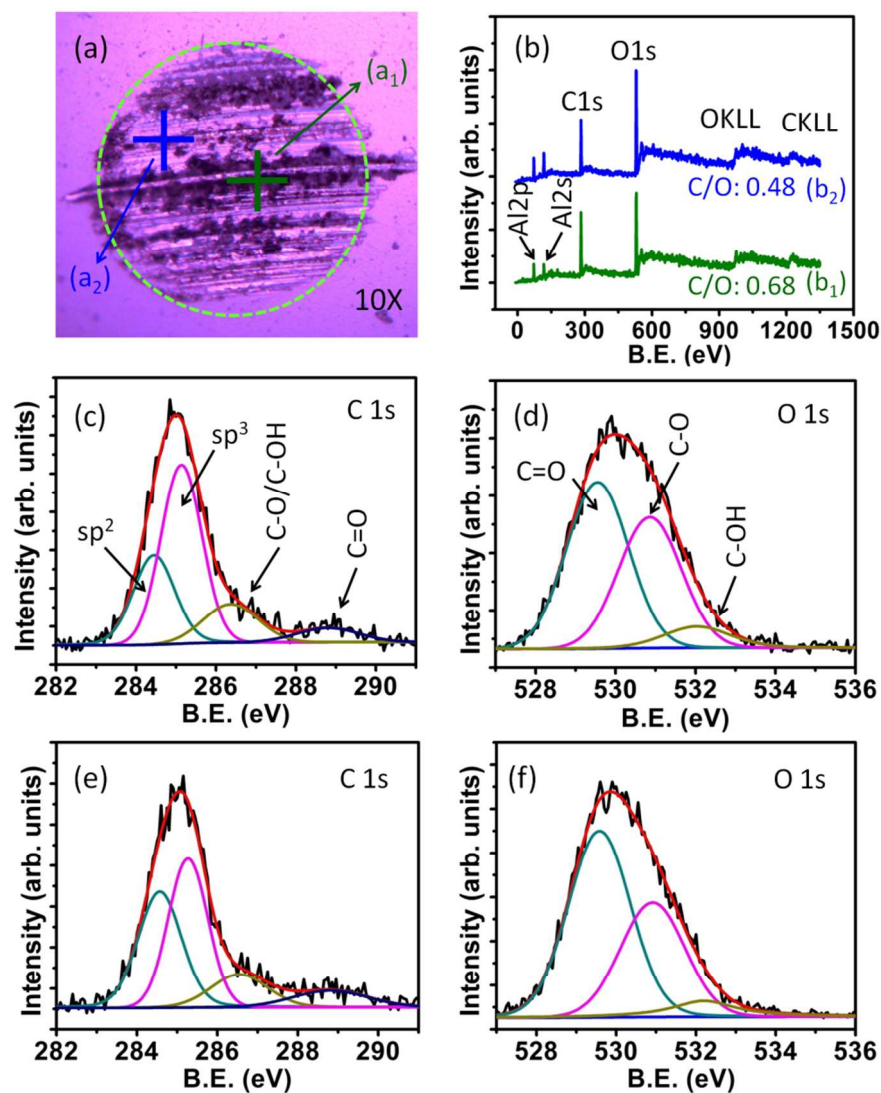


Figure 8. (a) Optical image of ball scar in HV-RT tribo-condition: (a₁) deformed and (a₂) less deformed region and corresponding survey XPS spectra of (b₁) and (b₂), respectively; HR-XPS of C1s and O1s of (c and d) deformed and (e and f) less deformed region, respectively.

In this condition, contribution of oxygen contamination is mainly due to exposure of film sample in ambient atmosphere after conducting the tribo-tests. Further, the location (b₂) in Figure 8a contains much oxygen contamination as shown by decrease in C/O ratio (Figure 8b). This could be related to the high surface reactivity of the deformed region. Moreover, HR-XPS showed significant increase in sp³/sp² ratio to 1.88 and 1.09 (Figure 8c and 8e) in two different locations

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3 indicated in optical image (Figure 8a). These values are much higher as compared to tribofilm
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5 formed in AA-RT tribo-condition. Furthermore, the sp^3/sp^2 value of 1.88 in deformed location is
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7 higher than virgin film surface and this is possibly associated to the conversion of sp^2 into
8
9 amorphization (a-C) and disordered sp^3 (t-aC) phase in high vacuum condition. This evidence is
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11 supported by phonon behavior of these phases analyzed by Raman spectroscopy (Figure 5).The
12
13 above mentioned phase transformation is realistic at high activation energy which is contributed
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15 by the high frictional energy in HV-RT tribo-condition. The photoelectron shift of O1s peaks is
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17 quite similar and comparable to the tribofilm formed in AA-RT tribo-condition, indicating
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19 surface contamination during exposure to ambient atmosphere. However, changes in intensity
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21 and photoelectron peak shift of C=O, C-O and C-OH groups are related to oxidation behavior of
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23 the carbon.
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29 In survey spectra, C/O ratio is much higher 2.46 and 2.42 at two different locations of the
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31 ball scar formed in HV-HT (Figure 9b) as compared to other two tribo-conditions. These are
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33 located as (a₁) and (a₂) in Figure 9a, respectively. Furthermore, this ratio is comparable to film
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35 surface exposed to high temperature (Figure S9a), signifying resistance to adsorption of oxygen
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37 contamination in HV-HT tribo-condition. The residual oxygen contamination thermally desorbs
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39 mainly in the high temperature and high vacuum condition due to the weakening of cohesive
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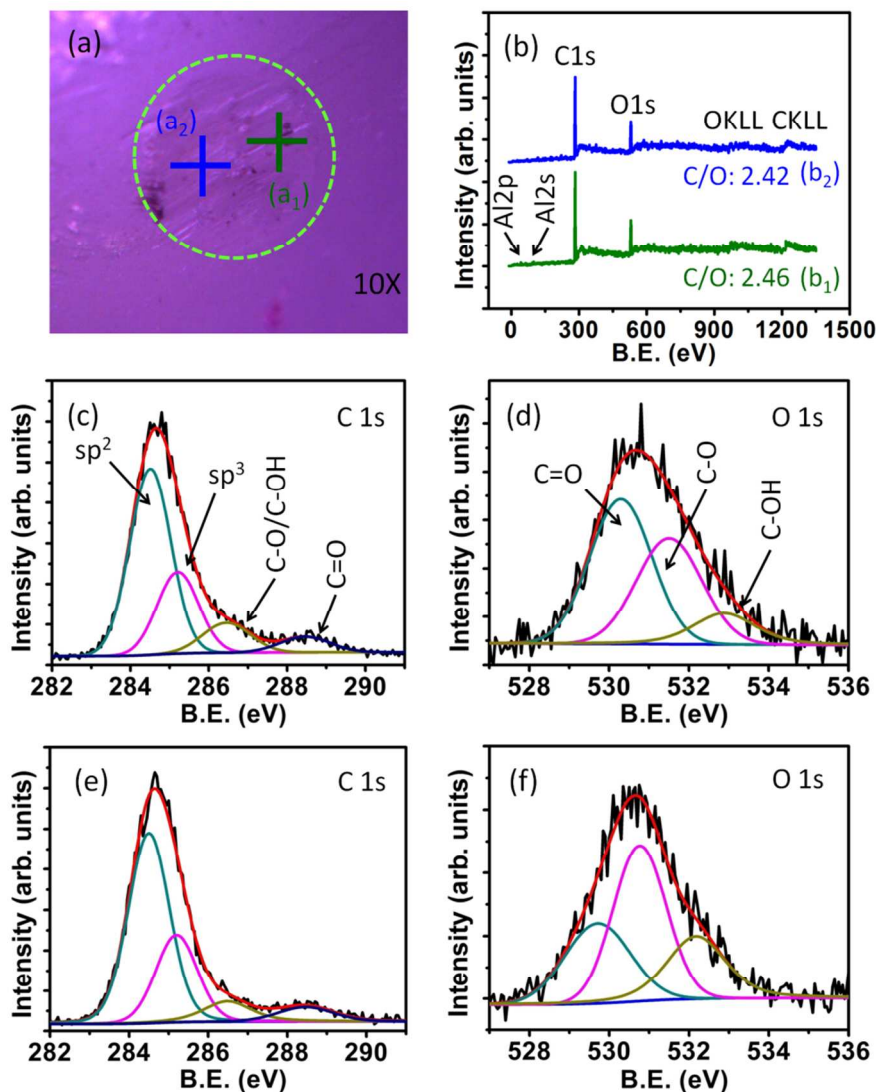


Figure 9. (a) Optical image of ball scar (HV-HT tribo-condition) locations: (a₁) and (a₂) and corresponding survey XPS spectra of (b₁) and (b₂), respectively; HR-XPS of C1s and O1s of (c and d) at location (a₁) and (e and f) at locations (a₂), respectively.

Interestingly, sp³/sp² ratio of tribofilm is reduced to 0.46 and 0.42 at two different locations of ball scar (Figure 9c and 9e) as indicated in the optical image (Figure 9a). These values are much lower than virgin film surface (Figure 2c) and directly indicate the significant conversion of sp³ into sp² phase. Such conversion was also evident in AA-RT tribo-condition to some extent but high temperature is energetically favorable for such a transformation.⁶⁰ This was indicated by the

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3 decrease in sp^3/sp^2 value to 0.57 when the film was exposed to high temperature (Figure S9b).
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5 Stress-induced conversion of sp^3 into sp^2 phase is dominating in AA-RT while stress and thermal
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7 energy both are governing factors for such conversion in HV-HT tribo-condition. Chemical
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9 characteristics of tribofilm in AA-RT and HV-HT are contrasting to HV-RT tribo-condition. The
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11 amorphization was dominated in HV-RT while graphitization occurred in AA-RT and HV-HT
12
13 tribo-conditions. The conversion of ordered sp^2 and sp^3 phases after the amorphization was
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15 restricted in HV-RT tribo-condition. However, nucleation of ordered carbon phase in AA-RT
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17 and HV-HT was realistic due to the favorable activation energy. The contribution of functional
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19 groups in C1s photoelectron shift is suppressed at location (a_2) as indicated in Figure 9a and
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21 corresponding spectra is shown in Figure 9e. The chemical shift of these functional groups in
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23 O1s photoelectron is different at two different locations (Figure 9d and 9f) and these are
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25 associated to the chemical affinity of surface.
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33 **5. Tribology Mechanisms.** Friction and wear values of UNCD NW films significantly differ
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35 depending upon the tribology test conditions (Figure 3). It is shown above that these values are
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37 high in HV-RT and significantly lower in HV-HT and AA-RT tribo-conditions. These
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39 contrasting behaviors could be explained by (a) passivation of carbon dangling bonds^{16,23} and (b)
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41 passivated graphitization mechanism at the sliding interfaces. Density functional theory
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43 calculations demonstrated that dissociation of H_2 and H_2O are energetically favorable for the
44
45 passivation of dangling bonds in diamond, leading to reduction in surface energy.⁶¹ This fact is
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47 also demonstrated experimentally using spectroscopic technique by Konicek *et al.* in UNCD
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49 films at ambient atmosphere and room temperature tribological condition.¹⁶ Moreover, low
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51 friction of UNCD films at 200°C was obtained in ambient atmosphere and room temperature
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3 condition and this was explained by passivation mechanism.⁴³ However, dissociative passivation
4 mechanism of dangling bonds by ambient atmospheric H₂ and H₂O is restricted in high-vacuum
5 tribo-condition (HV-RT). On the other hand, the HV-RT condition is governing factor for the
6 transformation of diamond and graphitic phase into t-aC and a-C structure. This is mainly
7 associated to tribo-contact stress and high frictional energy which restricts these carbon phases to
8 nucleate into ordered chemical structure in the absence of passivating media. This evidence is
9 clearly demonstrated by the Raman spectroscopy which showed increase in a-C and t-aC
10 structure at the deformed ball scar (Figure 5). Moreover, XPS comprehensively showed large
11 amount of sp³ fraction at the deformed ball contact (Figure 8). This is schematically presented in
12 Figure 10b and standard deviation of sp³/sp² value is given in Figure 10d which showed
13 significantly large ratio. Moreover, Raman spectroscopy results showed termination of TPA
14 phase from the tribolayer formed at ball scar (Figure 5c and 5d).
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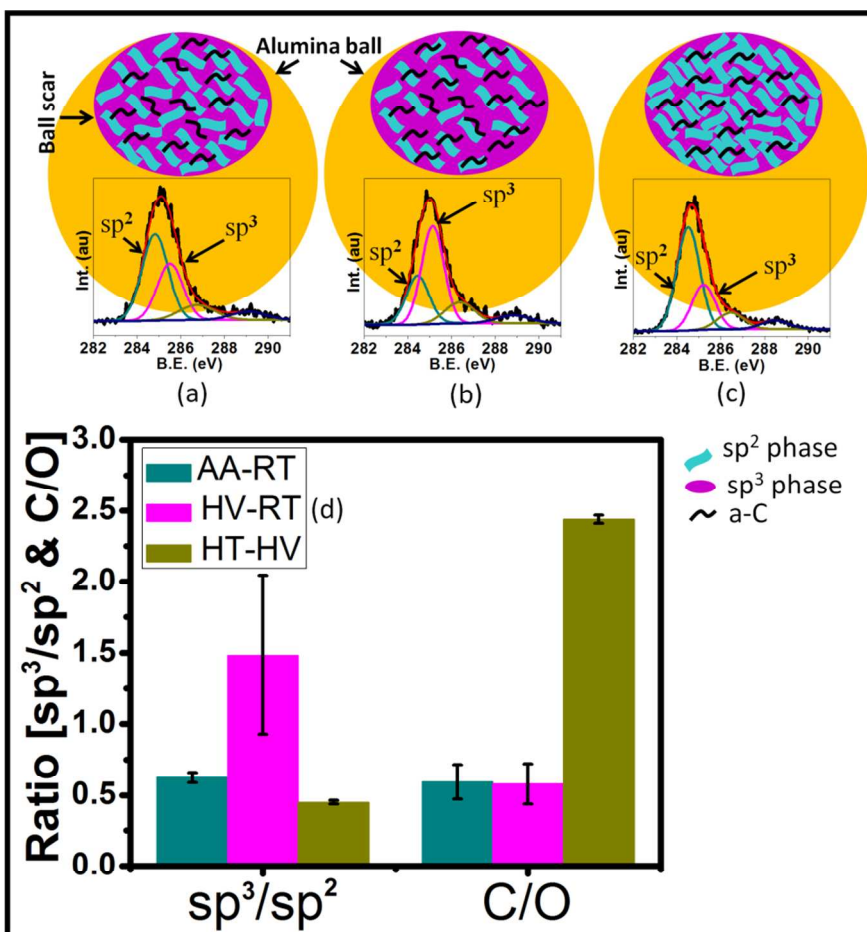


Figure 10. Schematic of carbon phase composition at tribologically deformed ball contact in (a) AA-RT (b) HV-RT and (c) HV-HT condition with the representation of typical HR-XPS and (d) bar graph of sp^3/sp^2 and C/O ratio with standard deviation.

The experimental facts revealed that in HV-RT tribo-condition, sliding is dominated between a-C and t-aC structure which is known to occupy the large fraction of dangling bonds in high vacuum condition.⁶² The dangling bonds of carbon atoms form covalent bonds across the sliding interfaces which greatly enhanced the shear resistance. Moreover, these phases do not exhibit lamellar lattice structure and hence do not have easy tangential shearing. This causes increase in friction coefficient and wear to significantly high value which ultimately leads to partial mechanical failure of film (Figure 3a). However, passivation of dangling bonds is

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3 energetically favorable in AA-RT tribo-condition which results in low friction coefficient and
4 high wear resistance. In this condition, it is believed that the dangling bonds are terminated with
5 either –OH or –H due to the dissociation of atmospheric H₂O.^{16,23,61} This was supported by the
6 increase in C–O and C=O bonding fractions.¹⁶ To support this, our results also showed increase
7 in oxygen and its functional groups inside the wear track in AA-RT condition (Figure 7).
8 Moreover, passivation of dangling bonds stabilizes the chemically distorted tribolayer of a-C and
9 t-aC into ordered sp² phase. Such a chemical distortion is occurred by mechanical deformation
10 during sliding process. Here, TPA phase is preserved with its structure at contact interfaces. This
11 evidence is clearly noticed by the XPS spectra (Figure 7) and also supported by the Raman
12 spectroscopy (Figure 4c and 4d). In this condition, low friction and high wear resistance of
13 UNCD NW film in AA-RT are governed by the passivation of dangling bonds and partial
14 graphitization of tribolayer formed at the alumina ball. This is schematically presented in Figure
15 10a. The bar graph in Figure 10d showed statistical evidence of sp³ to sp² transformation. This
16 indicates that the sliding occurs between the graphitized tribolayer of ball and UNCD NW film
17 and passivation was dominating mechanism during the interaction of sliding surfaces.
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38 Friction coefficient and wear almost vanishes in HV-HT which is contrasting to HV-RT
39 tribo-condition. In this case, atmospheric water vapor is restricted during tribology test and
40 passivation mechanism of dangling bonds at contact interfaces is energetically not favorable.
41 Therefore, in this condition, graphitization of the sliding interfaces can be considered for
42 improving the tribological properties significantly.⁴² The evidence of graphitized sliding
43 interfaces is well investigated by Raman spectroscopy (Figure 6) and XPS (Figure 9). For clear
44 understanding, graphitized ball scar is schematically given in Figure 10c and bar graph in Figure
45 10d. This showed decrease in sp³/sp² in HR XPS and significant increase in C/O ratio in survey
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3 spectra. The activation energy for graphitization is provided by film temperature during sliding
4 process in high-temperature tribology condition. Here, frictional shear is dominated between
5 hydrogenated graphitized interfaces that lead to ultra-low friction coefficient and wearless
6 behavior. The hydrogen passivation of graphitized phases is intrinsically carried out by TPA
7 phase as clearly observed by Raman spectroscopy (Figure 6). Basic mechanism which improved
8 the tribological properties is governed by the unique lamellar lattice structure of hydrogenated
9 sp^2 phase which is environment dependent⁶³ and shears easily with negligible tangential
10 resistance. However, tribological properties of UNCD films at high temperature and ambient
11 atmospheric condition were significantly degraded due to the oxidation which increases the shear
12 resistance.⁴³

27 28 **6. CONCLUSIONS**

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30 Tribological properties of UNCD NW films were investigated in AA-RT, HV-RT and HV-HT
31 tribo-conditions. HRTEM analysis directly showed ultranano diamond grains in the film which
32 was further supported by the Raman spectroscopy. Moreover, phase composition was
33 investigated by XPS analysis which showed significant amount of sp^3 phase of ultranano
34 diamond grains and grain boundary of UNCD occupied by a-C and sp^2 phases. Furthermore,
35 randomly oriented nanowall morphology of the films was analyzed by high-resolution SEM.
36 Raman spectroscopy and XPS confirmed the mechanochemical conversion of UNCD phase and
37 tribo-environment dependent changes in chemical characteristic of tribofilm at contact interfaces.
38 Friction coefficient was significantly high ~ 0.17 and wear induced film failure with wear loss of
39 0.006 nm/cycles was observed in HV-RT condition. In this case, passivation mechanism was
40 restricted and frictional shear transformed the diamond sp^3 into a-C and t-aC phases. However,
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3 passivation and graphitization were energetically favorable mechanisms in AA-RT tribo-
4 condition which reduced the friction coefficient and wear up to ~0.023 and 0.002 nm/cycles,
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6 respectively. Moreover, significant conversion of diamond sp^3 into graphitized phase in the
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8 presence of internal hydrogen of film was predominant mechanism for the superlow friction
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10 coefficient ~0.002 and ultra high wear resistance of 0.0016 nm/cycles in HV-HT tribo-condition.
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17 ASSOCIATED CONTENT

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19 ***Supporting Information.*** Friction coefficient of UNCD NW films in AA-RT, HV-RT and HV-
20 HT tribo-condition, SEM images of the wear track and deformed ball scars, EDS analysis of the
21 wear track and deformed ball scar, Quantitative Raman data of D, G and I(D)/I(G) ratio of wear
22 track in AA-RT, HV-RT and HV-HT tribo-condition, XPS spectra of UNCD NW films exposed
23 to high temperature. This material is available free of charge via Internet at <http://pubs.acs.org>.
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46 NOTES

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48 The authors declare no competing financial interest.
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52 ACKNOWLEDGMENTS

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TOC Graphic

